MOSPEC

U10C05 thru U10C20

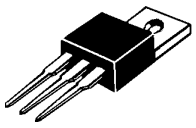
Switchmode
Dual Ultrafast Power Rectifiers

-- Designed for use in switching power supplies inverters and as free wheeling diodes. These state-of-the-art devices have the following features:

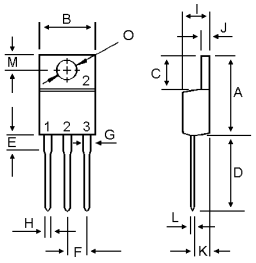
- ✳High Surge Capacity
- ✳Low Power Loss, High efficiency
- ✳Glass Passivated chip junctions
- ✳150 ^{O}C Operating Junction Temperature
- ✳Low Stored Charge Majority Carrier Conduction
- ✳Low Forward Voltage, High Current Capability
- ✳High-Switching Speed 35 Nanosecong Recovery Time
- ✳Plastic Material used Carries Underwriters Laboratory Flammability Classification 94V-O

ULTRA FAST RECTIFIERS

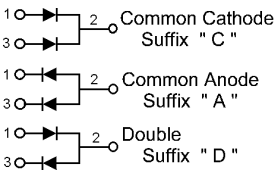
10 AMPERES
50-200 VOLTS



TO-220AB



DIM	MILLIMETERS	
	MIN	MAX
A	14.68	15.32
B	9.78	10.42
C	6.02	6.52
D	13.06	14.62
E	3.57	4.07
F	2.42	2.66
G	1.12	1.36
H	0.72	0.96
I	4.22	4.98
J	1.14	1.38
K	2.20	2.98
L	0.33	0.55
M	2.48	2.98
O	3.70	3.90



MAXIMUM RATINGS

Characteristic	Symbol	U10C05	U10C10	U10C15	U10C20	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	50	100	150	200	V
RMS Reverse Voltage	$V_{R(RMS)}$	35	70	105	140	V
Average Rectifier Forward Current Total Device (Rated V_R), T_C=100℃	$I_{F(AV)}$	5.0 10				A
Peak Repetitive Forward Current (Rate V_R, Square Wave, 20kHz)	I_{FM}	10				A
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware, single phase, 60Hz)	I_{FSM}	100				A
Operating and Storage Junction Temperature Range	T_J , T_{stg}	-65 to +150				℃

ELECTRIAL CHARACTERISTICS

Characteristic	Symbol	U10C05	U10C10	U10C15	U10C20	Unit
Maximum Instantaneous Forward Voltage (I_F =5.0 Amp T_C = 25℃) (I_F =5.0 Amp T_C = 125℃)	V_F	0.975 0.880				V
Maximum Instantaneous Reverse Current (Rated DC Voltage, T_C = 25℃) (Rated DC Voltage, T_C = 125℃)	I_R	5.0 200				uA
Reverse Recovery Time (I_F = 0.5 A, I_R =1.0 , I_{rr} =0.25 A)	T_{rr}	35				ns
Typical Junction Capacitance (Reverse Voltage of 4 volts & f=1 MHz)	C_P	55				pF

U10C05 Thru U10C20

FIG-1 TYPICAL FORWARD CHARACTERISITICS

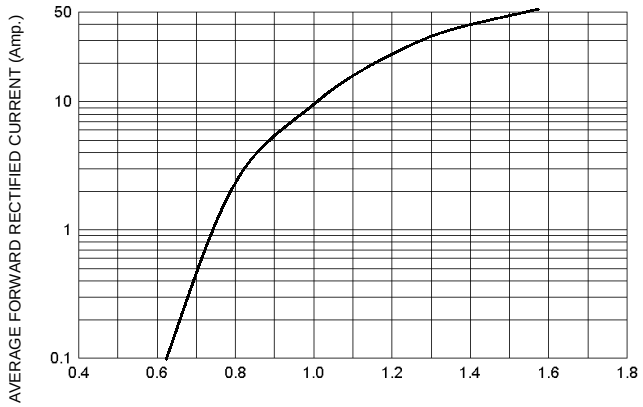


FIG-2 TYPICAL REVERSE CHARACTERISTICS

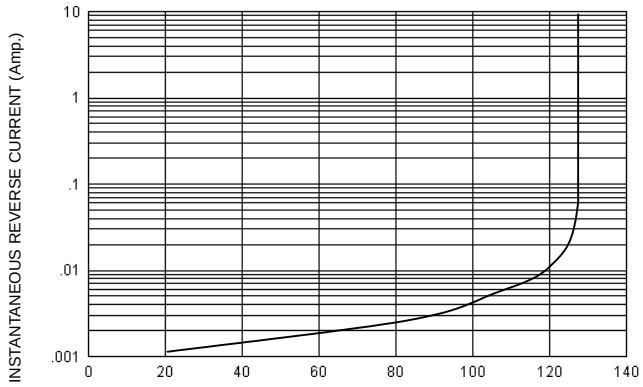


FIG-3 FORWARD CURRENT DERATING CURVE

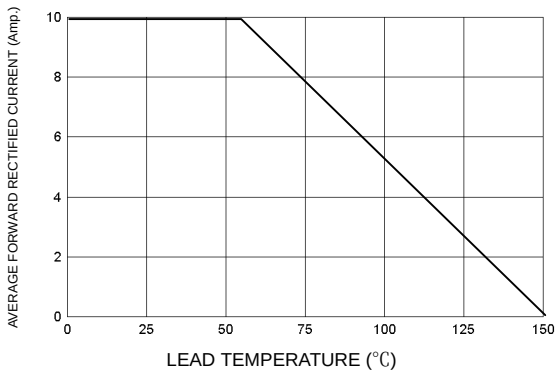


FIG-4TYPICAL JUNCTION CAPACITANCE

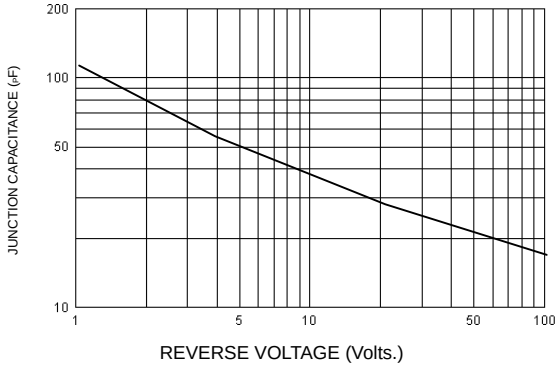
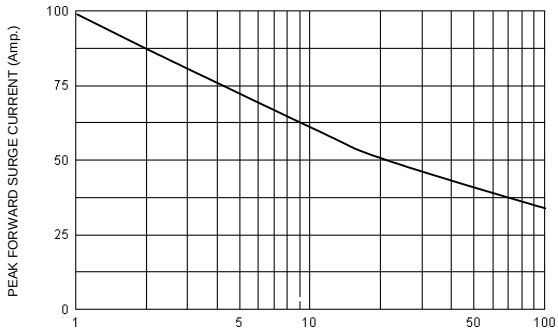
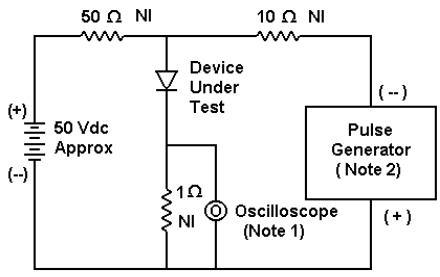
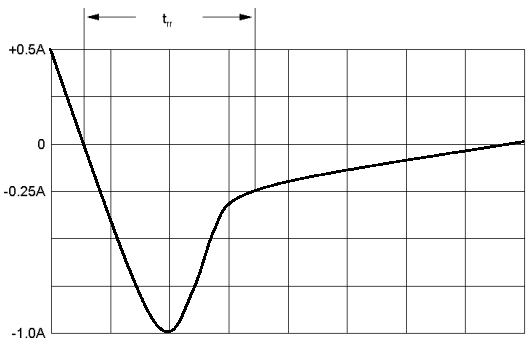


FIG-5PEAK FORWARD SURGE CURRENT





Notes:
1. Rise Time = 7 ns max. Input Impedance =1 M Ω , 22 pF
2. Rise Time = 10 ns max. Input Impedance = 50 Ω



Set time base for 10/20 ns/cm

FIG-6 Reverse Recovery Time Characteristic and Test Circuit Diagram

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